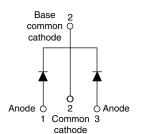


Vishay Semiconductors

Schottky Rectifier, 2 x 5 A





6.75 mJ

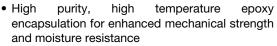
TO-220AB

 E_{AS}

PRODUCT SUMMARY Package TO-220AB I_{F(AV)} 2 x 5 A V_R 150 V V_F at I_F 0.73 V I_{RM} max. 7 mA at 125 °C T_J max. 175 °C Diode variation Common cathode

FEATURES

- 175 °C T_J operation
- Center tap configuration
- · Low forward voltage drop
- High frequency operation





FREE

- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-------------------------------------|---|-------------|----|--|--|--|--|
| SYMBOL CHARACTERISTICS VALUES UNITS | | | | | | | |
| I _{F(AV)} | Rectangular waveform | 10 | A | | | | |
| V _{RRM} | | 150 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 620 | A | | | | |
| V _F | 5 A _{pk} , T _J = 125 °C (per leg) | 0.73 | V | | | | |
| T _J | Range | - 55 to 175 | °C | | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|----------------|----------------|----------|--|--|
| PARAMETER | SYMBOL | VS-10CTQ150PbF | VS-10CTQ150-N3 | UNITS | | |
| Maximum DC reverse voltage | V _R | 150 | 150 | V | | |
| Maximum working peak reverse voltage | V _{RWM} | 130 | 130 | v | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---|----------------------|---|---|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| Maximum average per le | ~ I . | 50 % duty cycle at T _C = 155 °C, rectangular waveform | | 5 | А | |
| See fig. 5 per device | e I _{F(AV)} | | | 10 | | |
| Maximum peak one cycle non-repetitive surge current per leg | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and with rated | 620 | Α | |
| See fig. 7 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 115 | A | |
| Non-repetitive avalanche energy per leg | | $T_{J} = 25 ^{\circ}\text{C}, I_{AS} = 0.30 \text{A}, L = 150 \text{mH}$ | | 6.75 | mJ | |
| Repetitive avalanche current per leg I _{AR} | | Current decaying linearly to ze Frequency limited by T _J maxim | | 0.30 | Α | |



VS-10CTQ150PbF, VS-10CTQ150-N3

Vishay Semiconductors

| ELECTRICAL SPECIFICATIONS | | | | | | |
|---|--------------------------------|---|-------------------------|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| | | 5 A | T 05 °C | 0.93 | | |
| Maximum forward voltage drop per leg | V (1) | 10 A | T _J = 25 °C | 1.10 | W | |
| See fig. 1 | V _{FM} ⁽¹⁾ | 5 A | T 105 °C | 0.73 | V | |
| | | 10 A | T _J = 125 °C | 0.86 | | |
| Maximum reverse leakage current per leg | I _{RM} ⁽¹⁾ | T _J = 25 °C | V Dataday | 0.05 | mA | |
| See fig. 2 | | T _J = 125 °C | V_R = Rated V_R | 7 | | |
| Threshold voltage | V _{F(TO)} | T T manyimayan | | 0.468 | V | |
| Forward slope resistance | r _t | $T_J = T_J$ maximum | | 28 | mΩ | |
| Maximum junction capacitance per leg | C _T | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C | | 200 | pF | |
| Typical series inductance per leg | L _S | Measured lead to lead 5 mm from package body | | 8.0 | nH | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|---------|-----------------------------------|--------------------------------------|-------------|------------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | - 55 to 175 | °C | |
| Maximum thermal resistance, junction to case per leg | | Б | DC enception | 3.50 | °C/W | |
| Maximum thermal resistance, junction to case per package | | R _{thJC} | DC operation | 1.75 | | |
| Typical thermal resistance, case to heatsink (only for TO-220) | | R _{thCS} | Mounting surface, smooth and greased | 0.50 | | |
| Approximate weight | | | | 2 | g | |
| Approximate weight | | | | 0.07 | OZ. | |
| Mounting to your | minimum | | | 6 (5) | kgf · cm | |
| Mounting torque | maximum | | | 12 (10) | (lbf \cdot in) | |
| Marking device | | | Case style TO-220AB | 10CT | Q150 | |



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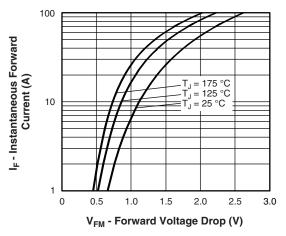


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

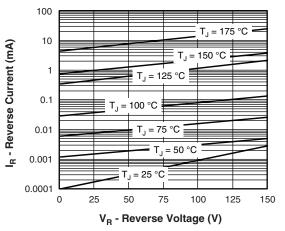


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

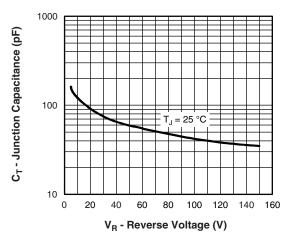


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

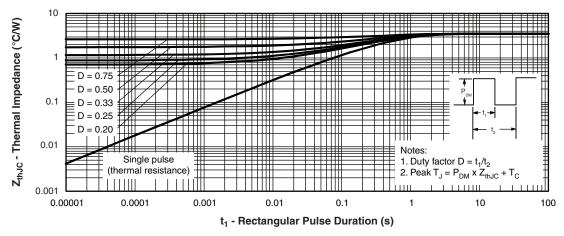


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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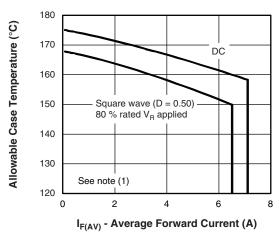


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

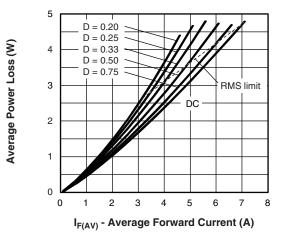


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

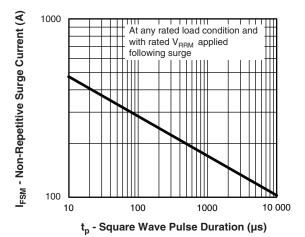


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

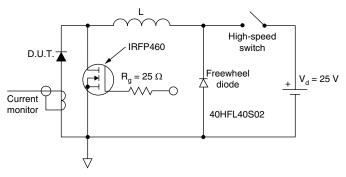


Fig. 8 - Unclamped Inductive Test Circuit

Note

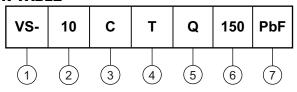
 $^{(1)}$ Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V

VS-10CTQ150PbF, VS-10CTQ150-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE





1 - Vishay Semiconductors product

2 - Current rating (10 = 10 A)

Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

6 - Voltage rating (150 = 150 V)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|---|----|------|-------------------------|--|--|--|
| PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | |
| VS-10CTQ150PbF | 50 | 1000 | Antistatic plastic tube | | | |
| VS-10CTQ150-N3 | 50 | 1000 | Antistatic plastic tube | | | |

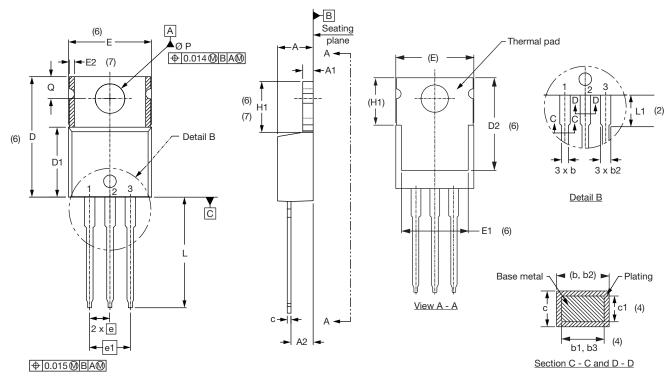
| LINKS TO RELATED DOCUMENTS | | | | | |
|-------------------------------------|--------------|--------------------------|--|--|--|
| Dimensions www.vishay.com/doc?95222 | | | | | |
| Part marking information | TO-220AB PbF | www.vishay.com/doc?95225 | | | |
| Part marking information | TO-220AB -N3 | www.vishay.com/doc?95028 | | | |



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|--------|--------|--------|-------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |

| SYMBOL | MILLIM | IETERS | INC | HES | NOTES |
|---------|------------|--------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| E | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| E2 | - | 0.76 | - | 0.030 | 7 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6, 7 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| θ | 90° to 93° | | 90° t | o 93° | |
| | | • | • | • | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



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Vishay

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